

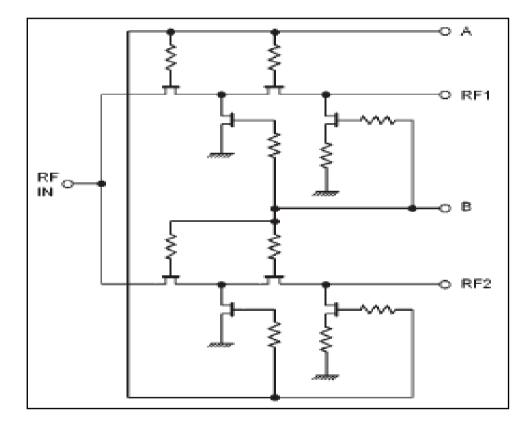
## **Product Description**

The RBS671 is a high performance Gallium Arsenide single pole double through broad band RF switch. It is suitable for use in broadband communications and instrumentation applications. The isolated port of the switch is terminated with a 50 ohm load. The switch is controlled by the application of complimentary 0V/-5V or 0/-8V signals to the control lines in accordance with the truth table below.

## **Functional Block Diagram**

### **Features**

- Broadband performance
- High Isolation; 45 dB typ at 1 GHz
- Ultra low DC power consumption





## **Specifications**

## **Absolute Maximum Ratings**

Name	Description	
Max Control Voltage	-8 V	
RF I/P Power	+30 dBm	
Operating Temperature Range	-40 to +85° C	

## **Electrical Performance**

## Typical performance at 25°C

Ambient temperature =  $25\pm3^{\circ}$ C, Zo =  $50 \Omega$ , Control voltage = 0V/-5V unless otherwise stated

Parameter	Condition	Min.	Тур.	Max.	Units
Insertion Loss <sup>1</sup>	DC – 1 GHz	-	0.8	1.2	dB
	1 – 3 GHz	-	1.2	1.5	dB
Isolation <sup>1</sup>	DC – 1 GHz	52	55	-	dB
	1 – 3 GHz	1 – 3 GHz 36		-	dB
Input Return Loss <sup>2</sup>	DC – 1 GHz	20	25	-	dB
	1 – 3 GHz	12	15	-	dB
Output Return Loss <sup>2</sup>	DC – 1 GHz	20	25	-	dB
	1 – 3 GHz	12	15	-	dB
P1dB power compression point <sup>3</sup>	0/-5 V control; 50 MHz		21	-	dBm
	0/-5 V control; 2 GHz		27	-	dBm
	0/-8 V control; 50 MHz		22	-	dBm
0/-8 V control; 2 GHz			30	-	dBm
Switching Speed	50% control to 10%90% RF		2.2	8	ns

### Notes

- Insertion loss and Isolation measured between RF Input and any output.
  Return Loss measured in low loss switch state.
  Input power at which insertion loss compresses by 1dB.



# **Preliminary Data**

0

-10

-20

-30

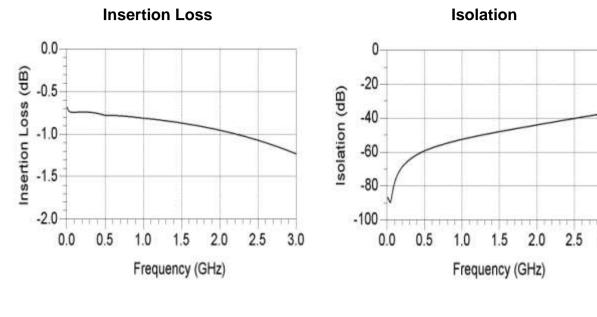
-40

0.0

0.5

1.0

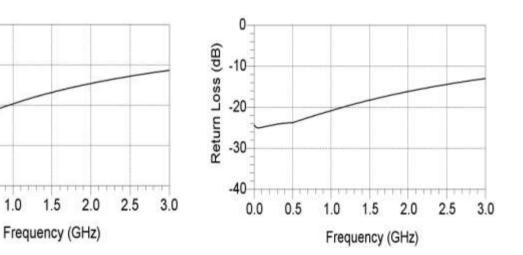
Return Loss (dB)



Input Return Loss

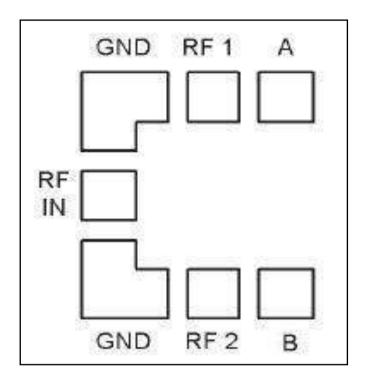
**Output Return Loss** 

3.0





# Chip Outline Diagram



Die size: 1.4 X 1.5 mm Minimum Bond pad size: 120  $\mu m$  x 120  $\mu m$  Die thickness: 200  $\mu m$ 

## Switching Truth Table

Α	В	RFIN-RF1	RFIN-RF2
0 V	-5 V	Low Loss	Isolated
-5 V	0 V	Isolated	Low Loss



### http://www.rfarrays.com

### **Customer Service Locations**

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#### **Product Preview**

The document contains information from the product concept specification. RF Arrays Inc. reserves the right to change information at any time without notification.

### Preliminary Information

The document contains information from the design target specification. RF Arrays Inc. reserves the right to change information at any time without notification.

#### Production testing may not include testing of all parameters.

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